Low-ohmic single-pole double-throw analog switch

Rev. 6.2 — 3 December 2019

Product data sheet

1. General description

The NX3L1T5157 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z).

Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times. Low threshold digital input allows this device to be driven by 1.8 V logic levels in 3.3 V applications without significant increase in supply current I_{CC}. This makes it possible for the NX3L1T5157 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation. The NX3L1T5157 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y0 or Y1, or from Y0 or Y1 to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features and benefits

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - ◆ HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78 Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

| Type number | | | | | | | |
|--------------|------------------------|-------|---|---------|--|--|--|
| | marking ^[1] | Name | Description | Version | | | |
| NX3L1T5157GM | DI | XSON6 | plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm | SOT886 | | | |

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

4.1 Ordering options

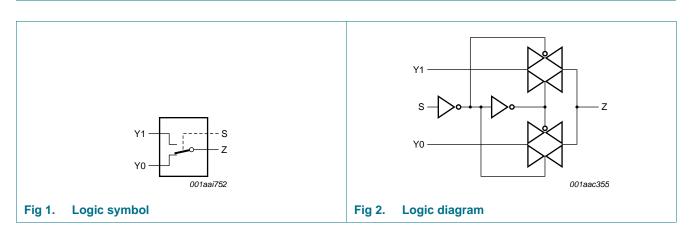
Table 2.Ordering options

| Type number | Orderable part number | Package | J | Minimum order quantity | Temperature |
|--------------|--------------------------|---------|--------------------------------------|---------------------------|--|
| NX3L1T5157GM | NX3L1T5157GM,115[1] | XSON6 | REEL 7" Q1 NDP | 5000 | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ |
| NX3L1T5157GM | NX3L1T5157GM,132[1] | XSON6 | REEL 7" Q3 NDP | 5000 | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ |
| NX3L1T5157GM | NX3L1T5157GMZ | XSON6 | REEL 7" Q1 NDP SSB ^[2] | 5000 | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ |
| NX3L1T5157GM | NX3L1T5157GMAZ | XSON6 | REEL 7" Q3 NDP SSB ^[2] | 5000 | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ |

 $\begin{tabular}{ll} [1] & \end{tabular} Will go EOL - migrate to new leadframe orderable part number. \end{tabular}$

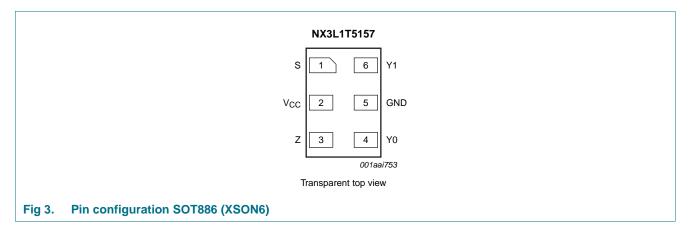
[2] This packing method uses a Static Shielding Bag (SSB) solution. Material is to be kept in the sealed bag between uses.

5. Functional diagram



6. **Pinning information**

6.1 Pinning



6.2 Pin description

| Table 3. | Pin descripti | ion |
|-----------------|---------------|-----------------------------|
| Symbol | Pin | Description |
| S | 1 | select input |
| V _{CC} | 2 | supply voltage |
| Z | 3 | common input or output |
| Y0 | 4 | independent input or output |
| GND | 5 | ground (0 V) |
| Y1 | 6 | independent input or output |

7. Functional description

Function table^[1] Table 4.

| Input S | Channel on |
|---------|------------|
| L | Y0 |
| Н | Y1 |

[1] H = HIGH voltage level; L = LOW voltage level.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|-------------------------|--|------------|------|-----------------------|------|
| V _{CC} | supply voltage | | | -0.5 | +4.6 | V |
| VI | input voltage | select input S | <u>[1]</u> | -0.5 | +4.6 | V |
| V _{SW} | switch voltage | | [2] | -0.5 | V _{CC} + 0.5 | V |
| l _{IK} | input clamping current | V _I < -0.5 V | | -50 | - | mA |
| I _{SK} | switch clamping current | $V_{\rm I}$ < -0.5 V or $V_{\rm I}$ > $V_{\rm CC}$ + 0.5 V | | - | ±50 | mA |
| I _{SW} | switch current | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current | | - | ±350 | mA |
| | | V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current | | - | ±500 | mA |
| T _{stg} | storage temperature | | | -65 | +150 | °C |
| P _{tot} | total power dissipation | $T_{amb} = -40 \text{ °C to } +125 \text{ °C}$ | [3] | - | 250 | mW |

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For XSON6 package: above 118 °C the value of Ptot derates linearly with 7.8 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------------|-------------------------------------|--------------------------------------|-----|-----------------|------|
| V _{CC} | supply voltage | | 1.4 | 4.3 | V |
| VI | input voltage | select input S | 0 | 4.3 | V |
| V _{SW} | switch voltage | [1] | 0 | V _{CC} | V |
| T _{amb} | ambient temperature | | -40 | +125 | °C |
| $\Delta t / \Delta V$ | input transition rise and fall rate | V _{CC} = 1.4 V to 4.3 V [2] | - | 200 | ns/V |

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

10. Static characteristics

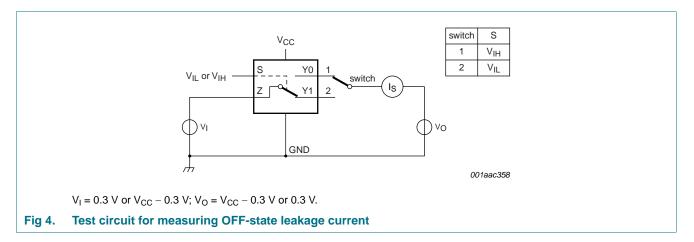
Table 7. Static characteristics

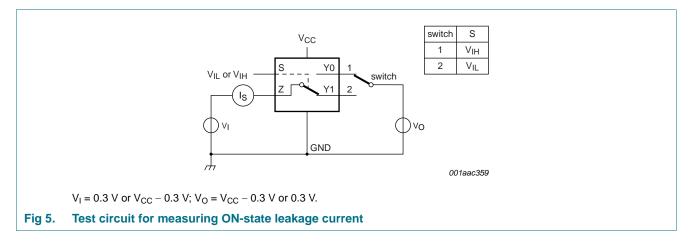
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

| Symbol | Parameter | Conditions | T, | _{amb} = 25 | °C | T _{amb} = −40 °C to +125 °C | | | Unit |
|---------------------|--------------------------|---|-----|---------------------|------|--------------------------------------|----------------|-----------------|------|
| | | | Min | Тур | Max | Min | Max (85 °C) | Max (125 °C) | |
| V _{IH} | HIGH-level | $V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$ | 0.9 | - | - | 0.9 | - | - | V |
| | input voltage | V _{CC} = 1.65 V to 1.95 V | 0.9 | - | - | 0.9 | - | - | V |
| | | V_{CC} = 2.3 V to 2.7 V | 1.1 | - | - | 1.1 | - | - | V |
| | | V _{CC} = 2.7 V to 3.6 V | 1.3 | - | - | 1.3 | - | - | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | 1.4 | - | - | 1.4 | - | - | V |
| V _{IL} | LOW-level | $V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$ | - | - | 0.3 | - | 0.3 | 0.3 | V |
| | input voltage | V _{CC} = 1.65 V to 1.95 V | - | - | 0.4 | - | 0.4 | 0.3 | V |
| | | V_{CC} = 2.3 V to 2.7 V | - | - | 0.4 | - | 0.4 | 0.4 | V |
| | | $V_{CC} = 2.7 \text{ V} \text{ to } 3.6 \text{ V}$ | - | - | 0.5 | - | 0.5 | 0.5 | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | - | 0.6 | - | 0.6 | 0.6 | V |
| I | input leakage current | select input S; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V | - | - | - | - | ±0.5 | ±1 | μA |
| I _{S(OFF)} | F) OFF-state leakage | Y0 and Y1 port; see <u>Figure 4</u> | | | | | | | |
| | current | V _{CC} = 1.4 V to 3.6 V | - | - | ±5 | - | ±50 | ±500 | nA |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | - | ±10 | - | ±50 | ±500 | nA |
| I _{S(ON)} | ON-state | Z port; see Figure 5 | | | | | | | |
| | leakage | $V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$ | - | - | ±5 | - | ±50 | ±500 | nA |
| | current | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | - | ±10 | - | ±50 | ±500 | nA |
| I _{CC} | supply current | $V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC} | | | | | | | |
| | | V _{CC} = 3.6 V | - | - | 100 | - | 690 | 6000 | nA |
| | | V _{CC} = 4.3 V | - | - | 150 | - | 800 | 7000 | nA |
| Δl _{CC} | additional | $V_{SW} = GND \text{ or } V_{CC}$ | | | | | | | |
| | supply current | $V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$ | - | 2.0 | 4.0 | - | 7 | 7 | μΑ |
| | | V _I = 2.6 V; V _{CC} = 3.6 V | - | 0.35 | 0.7 | - | 1 | 1 | μΑ |
| | | $V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$ | - | 7.0 | 10.0 | - | 15 | 15 | μΑ |
| | | V _I = 1.8 V; V _{CC} = 3.6 V | - | 2.5 | 4.0 | - | 5 | 5 | μΑ |
| | | V _I = 1.8 V; V _{CC} = 2.5 V | - | 50 | 200 | - | 300 | 500 | nA |
| CI | input capacitance | | - | 1.0 | - | - | - | - | pF |
| $C_{S(OFF)}$ | OFF-state capacitance | | - | 35 | - | - | - | - | pF |
| C _{S(ON)} | ON-state capacitance | | - | 130 | - | - | - | - | pF |

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10.1 Test circuits





10.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see <u>Figure 7</u> to <u>Figure 13</u>.

| Symbol | Parameter | Conditions | T _{amb} = | T_{amb} = –40 °C to +85 °C | | $T_{amb} = -40 \circ 0$ | Unit | |
|-----------------------|-------------------------|--|--------------------|------------------------------|------|-------------------------|------|---|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Max | |
| R _{ON(peak)} | ON resistance (peak) | $V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see Figure 6 | | | | | | |
| | | V _{CC} = 1.4 V | - | 1.6 | 3.7 | - | 4.1 | Ω |
| | | V _{CC} = 1.65 V | - | 1.0 | 1.6 | - | 1.7 | Ω |
| | | V _{CC} = 2.3 V | - | 0.55 | 0.8 | - | 0.9 | Ω |
| | | V _{CC} = 2.7 V | - | 0.5 | 0.75 | - | 0.9 | Ω |
| | | V _{CC} = 4.3 V | - | 0.5 | 0.75 | - | 0.9 | Ω |

Table 8. ON resistance ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

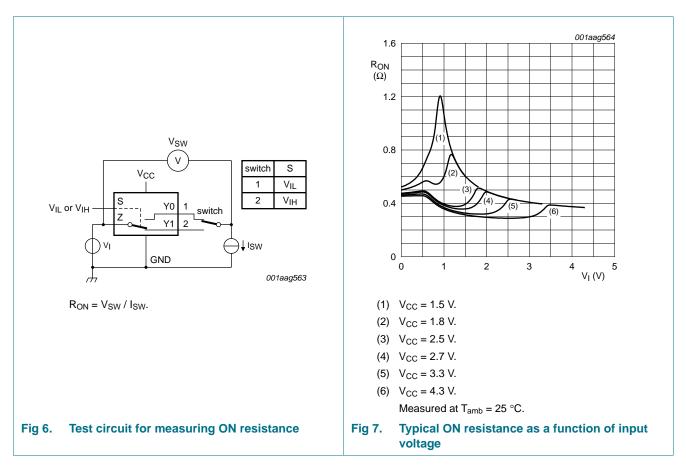
| Symbol | Parameter | Conditions | T _{amb} = | -40 °C to | o +85 °C | T_{amb} = -40 ° | C to +125 °C | Unit |
|---|-----------------------------|--|--------------------|-----------|----------|-------------------|--------------|------|
| | | | Min | Typ[1] | Max | Min | Max | |
| ΔR _{ON} ON resistance mismatch | | $V_{I} = GND \text{ to } V_{CC}; \qquad [2]$ $I_{SW} = 100 \text{ mA}$ | | | | | | |
| | between channels | V _{CC} = 1.4 V | - | 0.04 | 0.3 | - | 0.3 | Ω |
| | Charmeis | V _{CC} = 1.65 V | - | 0.04 | 0.2 | - | 0.3 | Ω |
| | | V _{CC} = 2.3 V | - | 0.02 | 0.08 | - | 0.1 | Ω |
| | | $V_{CC} = 2.7 V$ | - | 0.02 | 0.075 | - | 0.1 | Ω |
| | | $V_{CC} = 4.3 V$ | - | 0.02 | 0.075 | - | 0.1 | Ω |
| R _{ON(flat)} | ON resistance (flatness) | $V_{I} = GND \text{ to } V_{CC}; \qquad [3]$ $I_{SW} = 100 \text{ mA}$ | | | | | | |
| | | V _{CC} = 1.4 V | - | 1.0 | 3.3 | - | 3.6 | Ω |
| | | V _{CC} = 1.65 V | - | 0.5 | 1.2 | - | 1.3 | Ω |
| | | V _{CC} = 2.3 V | - | 0.15 | 0.3 | - | 0.35 | Ω |
| | | V _{CC} = 2.7 V | - | 0.13 | 0.3 | - | 0.35 | Ω |
| | | V _{CC} = 4.3 V | - | 0.2 | 0.4 | - | 0.45 | Ω |

[1] Typical values are measured at $T_{amb} = 25 \text{ °C}$.

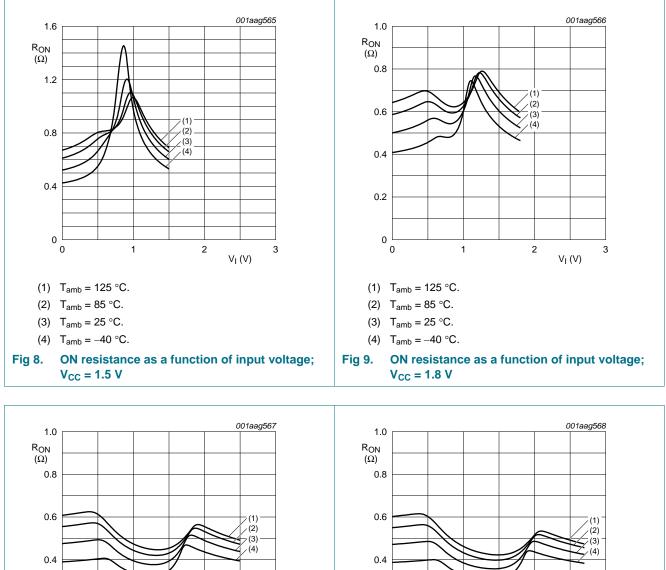
[2] Measured at identical V_{CC}, temperature and input voltage.

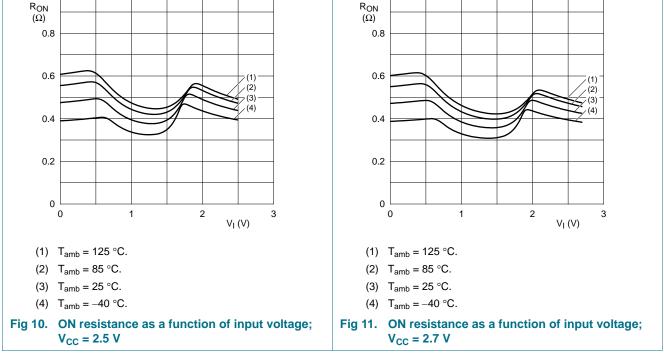
[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

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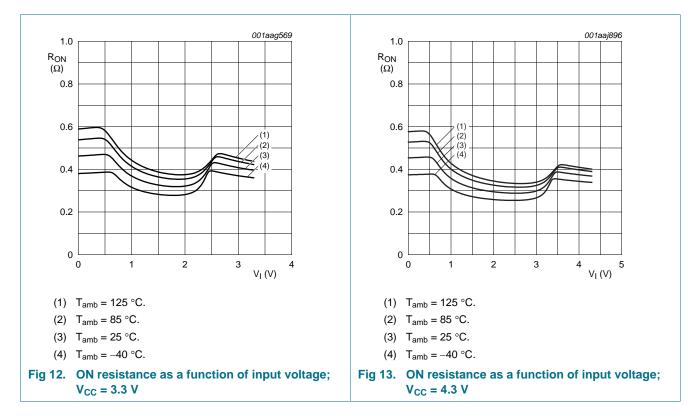


10.3 ON resistance test circuit and graphs





Low-ohmic single-pole double-throw analog switch



11. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 16.

| Symbol | Parameter | Conditions | | 25 °C | | –40 °C to +125 °C | | | Unit |
|------------------|--------------|--|-----|----------------------|-----|-------------------|----------------|-----------------|------|
| | | | Min | Typ <mark>[1]</mark> | Мах | Min | Мах (85 °С) | Max (125 °C) | |
| t _{en} | enable time | S to Z or Yn; see Figure 14 | | | | | | | |
| | | $V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$ | - | 50 | 90 | - | 120 | 120 | ns |
| | | V _{CC} = 1.65 V to 1.95 V | - | 36 | 70 | - | 80 | 90 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | - | 24 | 45 | - | 50 | 55 | ns |
| | | $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$ | - | 22 | 40 | - | 45 | 50 | ns |
| | | V_{CC} = 3.6 V to 4.3 V | - | 22 | 40 | - | 45 | 50 | ns |
| t _{dis} | disable time | S to Z or Yn; see Figure 14 | | | | | | | |
| | | V_{CC} = 1.4 V to 1.6 V | - | 32 | 70 | - | 80 | 90 | ns |
| | | V_{CC} = 1.65 V to 1.95 V | - | 20 | 55 | - | 60 | 65 | ns |
| | | V_{CC} = 2.3 V to 2.7 V | - | 12 | 25 | - | 30 | 35 | ns |
| | | V_{CC} = 2.7 V to 3.6 V | - | 10 | 20 | - | 25 | 30 | ns |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | 10 | 20 | - | 25 | 30 | ns |

Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 16.

| Symbol | Parameter | Conditions | | 25 °C | | –40 °C to +125 °C | | 5 °C | Unit |
|------------------|-------------------|--|-----|----------------------|-----|-------------------|----------------|-----------------|------|
| | | | Min | Typ <mark>[1]</mark> | Max | Min | Max (85 °C) | Max (125 °C) | |
| t _{b-m} | break-before-make | see Figure 15 [2] | | | | | | | |
| | time | V _{CC} = 1.4 V to 1.6 V | - | 19 | - | 9 | - | - | ns |
| | | V _{CC} = 1.65 V to 1.95 V | - | 17 | - | 7 | - | - | ns |
| | | V_{CC} = 2.3 V to 2.7 V | - | 13 | - | 4 | - | - | ns |
| | | V_{CC} = 2.7 V to 3.6 V | - | 10 | - | 3 | - | - | ns |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | - | 10 | - | 2 | - | - | ns |

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

11.1 Waveform and test circuits

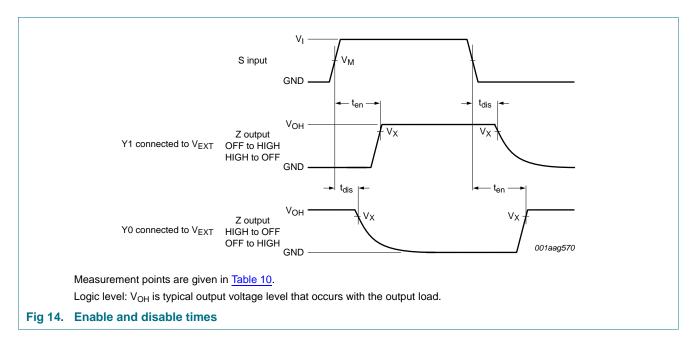
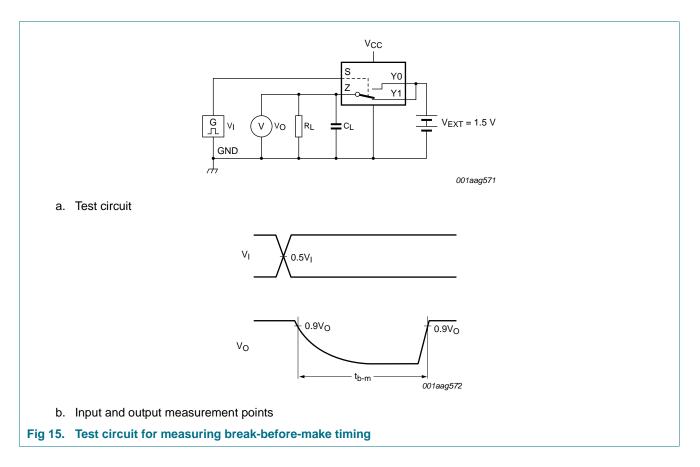


Table 10.Measurement points

| Supply voltage | Input | Output |
|-----------------|--------------------|--------------------|
| V _{CC} | V _M | V _x |
| 1.4 V to 4.3 V | 0.5V _{CC} | 0.9V _{OH} |

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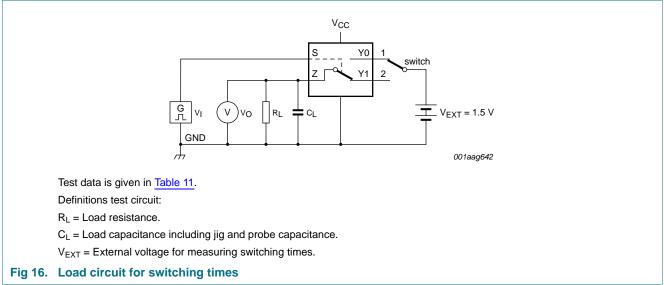


Table 11. Test data

| Supply voltage | Input | | Load | | |
|-----------------|-----------------|---------------------------------|-------|------|--|
| V _{cc} | VI | t _r , t _f | CL | RL | |
| 1.4 V to 4.3 V | V _{CC} | ≤ 2.5 ns | 35 pF | 50 Ω | |

NX3L1T5157

11.2 Additional dynamic characteristics

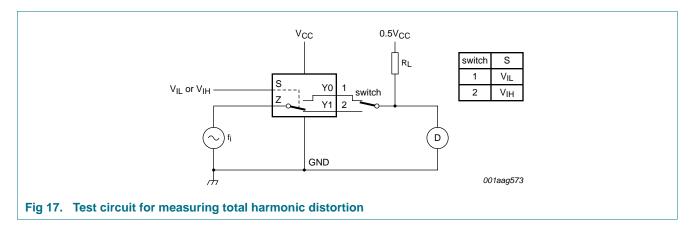
Table 12. Additional dynamic characteristics

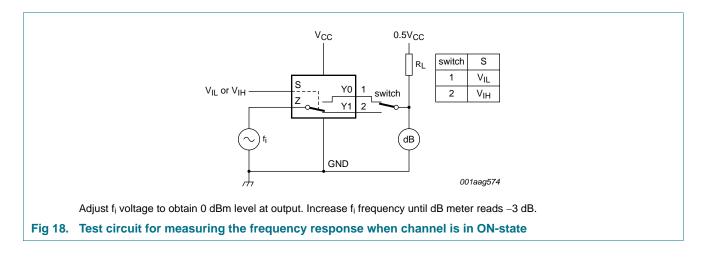
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

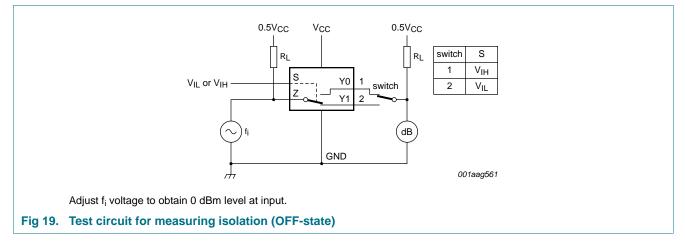
| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|---------------------|------------------------------|---|-----|-----|------|-----|------|
| THD | total harmonic distortion | $f_i = 20$ Hz to 20 kHz; $R_L = 32 \Omega$; see Figure 17 | [1] | | | | |
| | | V _{CC} = 1.4 V; V _I = 1 V (p-p) | | - | 0.15 | - | % |
| | | V _{CC} = 1.65 V; V _I = 1.2 V (p-p) | | - | 0.10 | - | % |
| | | V _{CC} = 2.3 V; V _I = 1.5 V (p-p) | | - | 0.02 | - | % |
| | | V _{CC} = 2.7 V; V _I = 2 V (p-p) | | - | 0.02 | - | % |
| | | V _{CC} = 4.3 V; V _I = 2 V (p-p) | | - | 0.02 | - | % |
| f _(-3dB) | -3 dB frequency response | $R_L = 50 \Omega$; see Figure 18 | [1] | | | | |
| | | $V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$ | | - | 60 | - | MHz |
| α_{iso} | isolation (OFF-state) | $f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } Figure 19$ | [1] | | | | |
| | | $V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$ | | - | -90 | - | dB |
| V _{ct} | crosstalk voltage | between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 20 | | | | | |
| | | V _{CC} = 1.4 V to 3.6 V | | - | 0.2 | - | V |
| | | $V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$ | | - | 0.3 | - | V |
| Q _{inj} | charge injection | $ f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; \\ R_{gen} = 0 \Omega; \text{ see } \underline{Figure \ 21} $ | | | | | |
| | | V _{CC} = 1.5 V | | - | 3 | - | рС |
| | | V _{CC} = 1.8 V | | - | 4 | - | рС |
| | | V _{CC} = 2.5 V | | - | 6 | - | рС |
| | | V _{CC} = 3.3 V | | - | 9 | - | рС |
| | | $V_{CC} = 4.3 V$ | | - | 15 | - | рС |
| | | | | 1 | | | |

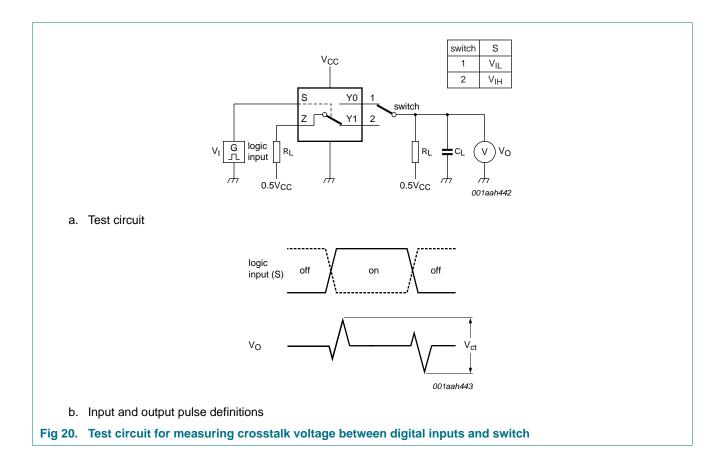
[1] f_i is biased at 0.5V_{CC}.

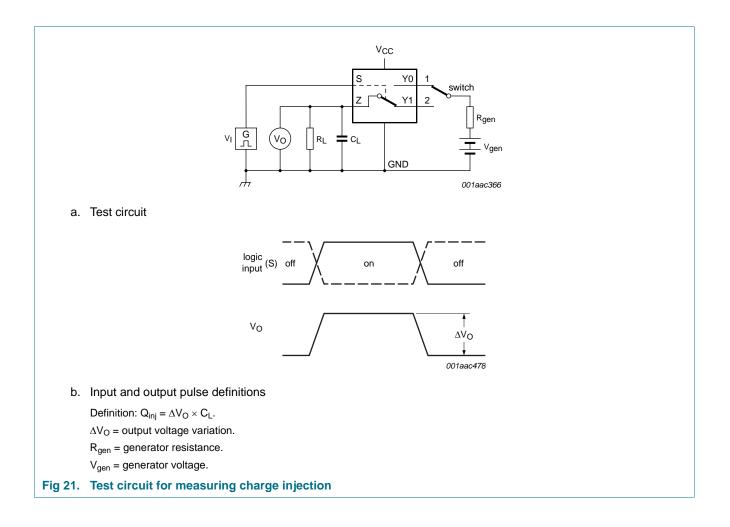
11.3 Test circuits











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12. Package outline

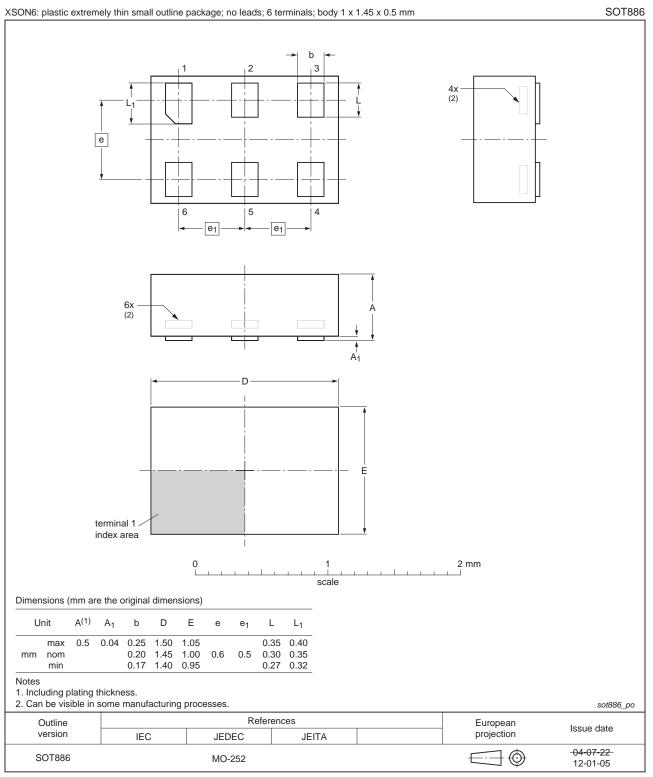


Fig 22. Package outline SOT886 (XSON6)

NX3L1T5157

13. Abbreviations

| Table 13. Abbreviations | | | |
|-------------------------|---|--|--|
| Acronym | Description | | |
| CDM | Charged Device Model | | |
| CMOS | Complementary Metal-Oxide Semiconductor | | |
| ESD | ElectroStatic Discharge | | |
| НВМ | Human Body Model | | |
| MM | Machine Model | | |
| PDA | Personal Digital Assistant | | |

14. Revision history

Table 14.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes | | |
|------------------|---------------------------------|--|---------------|------------------|--|--|
| NX3L1T5157 v.6.2 | 20191203 | Product data sheet | - | NX3L1T5157 v.6.1 | | |
| Modifications: | | Package SOT886 requiring SSB added. Refer to PCN number 201909001 XSON6 (SOT886) Assembly/Test Transfer from ATGD and ATSN to ATBK | | | | |
| NX3L1T5157 v.6.1 | 20161130 | Product data sheet | - | NX3L1T5157 v.6 | | |
| Modifications: | Added Section | on 13 "Packing information' | , - | | | |
| NX3L1T5157 v.6 | 20111108 | Product data sheet | - | NX3L1T5157 v.5 | | |
| Modifications: | Legal pages | updated. | | | | |
| NX3L1T5157 v.5 | 20110728 | Product data sheet | - | NX3L1T5157 v.4 | | |
| NX3L1T5157 v.4 | 20100324 | Product data sheet | - | NX3L1T5157 v.3 | | |
| NX3L1T5157 v.3 | 20100208 | Product data sheet | - | NX3L1T5157 v.2 | | |
| NX3L1T5157 v.2 | 20090417 | Product data sheet | - | NX3L1T5157 v.1 | | |
| NX3L1T5157 v.1 | 20080916 | Product data sheet | - | - | | |

15. Legal information

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| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
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| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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16. Contact information

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